

	Туре	L	#	Hits	Search Text	DBs	Time Stamp	Comment
1	BRS	L1		1365	359/290,291,295,214.c cls.	USPA T; US-P GPUB; EPO; JPO; DERW ENT	2004/04/2 6 16:14	
2	BRS	L2		1700	372/98,99.ccls.	USPA T; US-P GPUB; EPO; JPO; DERW ENT	2004/04/2 6 16:15	-
3	BRS	L4		0	:	USPA T; US-P GPUB ; EPO; JPO; DERW ENT	2004/04/2 6 16:18	
4	BRS	L5		0	2 and 3	USPA T; US-P GPUB; EPO; JPO; DERW ENT	2004/04/2 6 16:18	
5	BRS	L3		1	(laser with reflector) and (reflector with dielectric with layer) and (thin with film with resistor)	USPA T; US-P GPUB; EPO; JPO; DERW ENT	2004/04/2 6 17:48	

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	Type	L	#	Hits	Search Text	DBs	Time Stamp	Comment
6	BRS	L6	?: !:	317	(laser) and (dielectric with layer) and (thin with film with resistor)	USPA T; US-P GPUB; EPO; JPO; DERW ENT	2004/04/2 6 16:20	
7	BRS	L 7		68	(mirror) and (dielectric with layer) and (thin with film with resistor)	USPA T; US-P GPUB; EPO; JPO; DERW ENT	2004/04/2 6 16:21	
8	BRS	L1	2	723	359/291.ccls.	USPA T; US-P GPUB; EPO; JPO; DERW ENT	2004/04/2 6 17:23	
9	BRS	L1	3	486	359/290.ccls.	USPA T; US-P GPUB ; EPO; JPO; DERW ENT	2004/04/2 6 17:23	
10	BRS	L1	4	246	12 and 13	USPA T; US-P GPUB; EPO; JPO; DERW ENT	2004/04/2 6 17:23	

Time Comment Type L # Hits Search Text DBs Stamp s USPA Т; (laser with US-P reflector) and GPUB 2004/04/2 (reflector with BRS L15 0 11 6 17:25 dielectric with EPO; layer) and 14 JPO; DERW ENT USPA Т; US-P GPUB (laser with 2004/04/2 12 BRS L16 1 6 17:24 reflector) and 14 EPO; JPO; DERW ENT USPA Т; US-P GPUB (reflector with 2004/04/2 dielectric with 13 BRS L17 3 6 17:26 layer) and 14 EPO; JPO; DERW ENT USPA Т; US-P GPUB 2004/04/2 14 BRS L20 2611 257/536-543.ccls. 6 17:47 EPO; JPO; DERW ENT USPA Т; US-P GPUB 2004/04/2 BRS 15 L21 0 3 and 20 6 17:48 EPO; JPO; DERW ENT

Jr. 112

Time Comment Type | L # | Hits Search Text DBs Stamp 8 USPA T; US-P (reflector) SAME GPUB (dielectric adj 2004/04/2 BRS L1 1 0 layer) SAME (film adj 6 12:48 EPO; resistor) JPO; DERW ENT USPA T; US-P GPUB 2 AND (thin adj film 2004/04/2 BRS L3 2 1 adj resistor) 6 12:49 EPO; JPO; DERW ENT USPA Т; US-P (reflector) and GPUB (dielectric adj 2004/04/2 BRS 3 L4 6 layer) and (thin adj 6 12:51 EPO; film adj resistor) JPO; DERW ENT USPA Τ; US-P GPUB 2 AND (FILM ADJ 2004/04/2 BRS L5 1 4 RESISTOR) 6 13:08 EPO; JPO; DERW ENT USPA T; US-P (reflector) SAME GPUB 2004/04/2 (dielectric adj L25 BRS 485 6 13:08 layer) EPO; JPO; DERW ENT

5 2 3 %

	Туре	L #	Hits	Search Text	DBs	Time Stamp	Comment s
6	BRS	L6	1419	359/629,726.CCLS.	USPA T; US-P GPUB; EPO; JPO; DERW ENT	2004/04/2 6 14:44	
7	BRS	L 7	1	2 AND 6	USPA T; US-P GPUB; EPO; JPO; DERW ENT	2004/04/2 6 14:45	
8	BRS	L8	1349	372/20.CCLS.	USPA T; US-P GPUB; EPO; JPO; DERW ENT	2004/04/2 6 14:46	·
9	BRS	L9	9	2 AND 8	USPA T; US-P GPUB; EPO; JPO; DERW ENT	2004/04/2 6 14:46	

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